# **Octal 3-State Noninverting D Flip-Flop**

## High–Performance Silicon–Gate CMOS

The MC74HC574A is identical in pinout to the LS574. The device inputs are compatible with standard CMOS outputs; with pull–up resistors, they are compatible with LSTTL outputs.

Data meeting the set-up time is clocked to the outputs with the rising edge of the Clock. The Output Enable input does not affect the states of the flip-flops but when Output Enable is high, all device outputs are forced to the high-impedance state. Thus, data may be stored even when the outputs are not enabled.

The HC574A is identical in function to the HC374A but has the flip–flop inputs on the opposite side of the package from the outputs to facilitate PC board layout.

### Features

- Output Drive Capability: 15 LSTTL Loads
- Outputs Directly Interface to CMOS, NMOS, and TTL
- Operating Voltage Range: 2.0 to 6.0 V
- Low Input Current: 1.0 μA
- In Compliance with the Requirements Defined by JEDEC Standard No. 7 A
- Chip Complexity: 266 FETs or 66.5 Equivalent Gates
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q100 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant

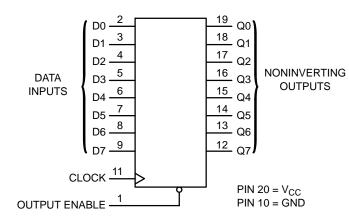


Figure 1. Logic Diagram



## **ON Semiconductor®**

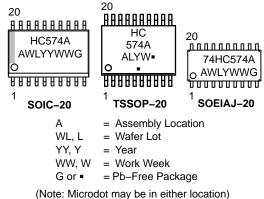
http://onsemi.com



PIN ASSIGNMENT

| OUTPUT   |                |                      |  |
|----------|----------------|----------------------|--|
| ENABLE 🗖 | 1 <sub>0</sub> | 20 🗖 V <sub>CC</sub> |  |
| D0 🗖     | 2              | 19 🗖 Q0              |  |
| D1 🗖     | 3              | 18 🗖 Q1              |  |
| D2 🗖     | 4              | 17 🗖 Q2              |  |
| D3 🗖     | 5              | 16 🗖 Q3              |  |
| D4 🗖     | 6              | 15 📩 Q4              |  |
| D5 🗖     | 7              | 14 🗖 Q5              |  |
| D6 🗖     | 8              | 13 🗖 Q6              |  |
| D7 🗖     | 9              | 12 🗖 Q7              |  |
| GND 🗆    | 10             |                      |  |





| FU | NC. | ΓΙΟΝ | ι τα | BLE |  |
|----|-----|------|------|-----|--|

| I GNOTION IABEE |        |        |           |  |  |
|-----------------|--------|--------|-----------|--|--|
|                 | Inputs | Output |           |  |  |
| OE              | Clock  | D      | Q         |  |  |
| L               | 7      | Н      | Н         |  |  |
| L               | _      | L      | L         |  |  |
| L               | L,H,   | Х      | No Change |  |  |
| н               | Х      | Х      | Z         |  |  |
|                 |        |        |           |  |  |

X = Don't Care

Z = High Impedance

#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

| Design Criteria                 | Value  | Units |
|---------------------------------|--------|-------|
| Internal Gate Count*            | 66.5   | ea.   |
| Internal Gate Propagation Delay | 1.5    | ns    |
| Internal Gate Power Dissipation | 5.0    | μW    |
| Speed Power Product             | 0.0075 | рJ    |

\*Equivalent to a two-input NAND gate.

#### **MAXIMUM RATINGS**

| Symbol               | F                                      | Parameter  | Value                         | Unit |
|----------------------|--|--|-------------------------------|------|
| V <sub>CC</sub>      | DC Supply Voltage                      |  | -0.5 to +7.0                  | V    |
| VI                   | DC Input Voltage                       |  | -0.5 to V <sub>CC</sub> + 0.5 | V    |
| Vo                   | DC Output Voltage                      | (Note 1)   | –0.5 to V <sub>CC</sub> + 0.5 | V    |
| I <sub>IK</sub>      | DC Input Diode Current                 |  | ±20                           | mA   |
| Ι <sub>ΟΚ</sub>      | DC Output Diode Current                |  | ±35                           | mA   |
| Ι <sub>Ο</sub>       | DC Output Sink Current                 |  | ±35                           | mA   |
| I <sub>CC</sub>      | DC Supply Current per Supply Pin       |  | ±75                           | mA   |
| I <sub>GND</sub>     | DC Ground Current per Ground Pin       |  | ±75                           | mA   |
| T <sub>STG</sub>     | Storage Temperature Range              |  | -65 to +150                   | °C   |
| ΤL                   | Lead Temperature, 1 mm from Case f     | or 10 Seconds  | 260                           | °C   |
| TJ                   | Junction Temperature under Bias        |  | +150                          | °C   |
| $\theta_{JA}$        | Thermal Resistance                     | SOIC<br>TSSOP  | 96<br>128                     | °C/W |
| PD                   | Power Dissipation in Still Air at 85°C | SOIC<br>TSSOP  | 500<br>450                    | mW   |
| MSL                  | Moisture Sensitivity                   |  | Level 1                       |      |
| F <sub>R</sub>       | Flammability Rating                    | Oxygen Index: 30% – 35%  | UL 94 V–0 @ 0.125 in          |      |
| V <sub>ESD</sub>     | ESD Withstand Voltage                  | Human Body Model (Note 2)<br>Machine Model (Note 3)<br>Charged Device Model (Note 4) | > 4000<br>> 300<br>> 1000     | V    |
| I <sub>Latchup</sub> | Latchup Performance                    | Above $V_{CC}$ and Below GND at 85°C (Note 5)  | ±300                          | mA   |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

I<sub>O</sub> absolute maximum rating must be observed.
 Tested to EIA/JESD22-A114-A.

3. Tested to EIA/JESD22-A115-A.

4. Tested to JESD22-C101-A.

5. Tested to EIA/JESD78.

#### **RECOMMENDED OPERATING CONDITIONS**

| Symbol                          | Parameter                                |   |             | Max                | Unit |
|---------------------------------|--|---|-------------|--------------------|------|
| V <sub>CC</sub>                 | DC Supply Voltage                        | (Referenced to GND)   | 2.0         | 6.0                | V    |
| V <sub>I</sub> , V <sub>O</sub> | DC Input Voltage, Output Voltage         | (Referenced to GND)   | 0           | V <sub>CC</sub>    | V    |
| T <sub>A</sub>                  | Operating Temperature, All Package Types |   | -55         | +125               | °C   |
| t <sub>r</sub> , t <sub>f</sub> | Input Rise and Fall Time (Figure 2)      | V <sub>CC</sub> = 2.0 V<br>V <sub>CC</sub> = 4.5 V<br>V <sub>CC</sub> = 6.0 V | 0<br>0<br>0 | 1000<br>500<br>400 | ns   |

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

6. Unused inputs may not be left open. All inputs must be tied to a high- or low-logic input voltage level.

## MC74HC574A

|                 |   |  | V <sub>CC</sub>  | Guara                     | Guaranteed Limit          |                           |    |
|-----------------|---|--|--|---------------------------|---------------------------|---------------------------|----|
| Symbol          | Parameter   | Test Conditions  | V $-55 \text{ to } 25^{\circ}\text{C} \leq 85^{\circ}\text{C} \leq 12$ |                           | ≤ 125°C                   | 5°C Unit                  |    |
| V <sub>IH</sub> | Minimum High-Level Input<br>Voltage               | $\begin{split} V_{out} &= V_{CC} - 0.1 \text{ V} \\  I_{out}  &\leq 20 \ \mu \text{A} \end{split}$   | 2.0<br>3.0<br>4.5<br>6.0   | 1.5<br>2.1<br>3.15<br>4.2 | 1.5<br>2.1<br>3.15<br>4.2 | 1.5<br>2.1<br>3.15<br>4.2 | V  |
| V <sub>IL</sub> | Maximum Low–Level Input<br>Voltage                | $V_{out} = 0.1 V$<br>$ I_{out}  \le 20 \mu A$  | 2.0<br>3.0<br>4.5<br>6.0   | 0.5<br>0.9<br>1.35<br>1.8 | 0.5<br>0.9<br>1.35<br>1.8 | 0.5<br>0.9<br>1.35<br>1.8 | V  |
| V <sub>OH</sub> | Minimum High–Level Output<br>Voltage              | $\begin{array}{l} V_{in} = V_{IH} \\  I_{out}  \leq 20 \ \mu A \end{array}$  | 2.0<br>4.5<br>6.0  | 1.9<br>4.4<br>5.9         | 1.9<br>4.4<br>5.9         | 1.9<br>4.4<br>5.9         | V  |
| V <sub>OH</sub> | Minimum High–Level Output<br>Voltage              | $ \begin{array}{ll} V_{in} = V_{IH} & \qquad &  I_{out}  \leq 2.4 \text{ mA} \\ &  I_{out}  \leq 6.0 \text{ mA} \\ &  I_{out}  \leq 7.8 \text{ mA} \end{array} $ | 3.0<br>4.5<br>6.0  | 2.48<br>3.98<br>5.48      | 2.34<br>3.84<br>5.34      | 2.2<br>3.7<br>5.2         | V  |
| V <sub>OL</sub> | Maximum Low–Level Output<br>Voltage               | $\begin{array}{l} V_{in} = V_{IL} \\  I_{out}  \leq 20 \ \mu A \end{array}$  | 2.0<br>4.5<br>6.0  | 0.1<br>0.1<br>0.1         | 0.1<br>0.1<br>0.1         | 0.1<br>0.1<br>0.1         | V  |
|                 |   | $ \begin{array}{ll} V_{in} = V_{IL} &  I_{out}  \leq 2.4 \text{ mA} \\  I_{out}  \leq 6.0 \text{ mA} \\  I_{out}  \leq 7.8 \text{ mA} \end{array} $              | 3.0<br>4.5<br>6.0  | 0.26<br>0.26<br>0.26      | 0.33<br>0.33<br>0.33      | 0.4<br>0.4<br>0.4         |    |
| l <sub>in</sub> | Maximum Input Leakage<br>Current                  | V <sub>in</sub> = V <sub>CC</sub> or GND   | 6.0  | ±0.1                      | ±1.0                      | ±1.0                      | μΑ |
| I <sub>OZ</sub> | Maximum Three–State<br>Leakage Current            | Output in High–Impedance State<br>$V_{in} = V_{IL} \text{ or } V_{IH}$<br>$V_{out} = V_{CC} \text{ or GND}$  | 6.0  | ±0.5                      | ±5.0                      | ±10                       | μA |
| I <sub>CC</sub> | Maximum Quiescent Supply<br>Current (per Package) | $V_{in} = V_{CC} \text{ or GND}$<br>$I_{out} = 0 \ \mu A$  | 6.0  | 4.0                       | 40                        | 160                       | μΑ |

### DC ELECTRICAL CHARACTERISTICS (Voltages Referenced to GND)

## MC74HC574A

|  |  | Guara  |  |   |  |
|--|--|--|--|---|--|
| Parameter  | v  | –55 to 25°C  | ≤ 85°C   | ≤ 125°C   | Unit   |
| Maximum Clock Frequency (50% Duty Cycle)<br>(Figures 2 and 5)      | 2.0<br>3.0<br>4.5<br>6.0   | 6.0<br>15<br>30<br>35  | 4.8<br>10<br>24<br>28  | 4.0<br>8.0<br>20<br>24  | MHz  |
| Maximum Propagation Delay, Clock to Q<br>(Figures 2 and 5)         | 2.0<br>3.0<br>4.5<br>6.0   | 160<br>105<br>32<br>27   | 200<br>145<br>40<br>34   | 240<br>190<br>48<br>41  | ns   |
| Maximum Propagation Delay, Output Enable to Q<br>(Figures 3 and 6) | 2.0<br>3.0<br>4.5<br>6.0   | 150<br>100<br>30<br>26   | 190<br>125<br>38<br>33   | 225<br>150<br>45<br>38  | ns   |
| Maximum Propagation Delay, Output Enable to Q<br>(Figures 3 and 6) | 2.0<br>3.0<br>4.5<br>6 0   | 140<br>90<br>28<br>24  | 175<br>120<br>35<br>30   | 210<br>140<br>42<br>36  | ns   |
| Maximum Output Transition Time, any Output<br>(Figures 2 and 5)    | 2.0<br>3.0<br>4.5<br>6.0   | 60<br>27<br>12<br>10   | 75<br>32<br>15<br>13   | 90<br>36<br>18<br>15  | ns   |
| Maximum Input Capacitance  | •  | 10   | 10   | 10  | pF   |
| Maximum Three–State Output Capacitance, Output in High-<br>State   | -Impedance   | 15   | 15   | 15  | pF   |
|  | Maximum Clock Frequency (50% Duty Cycle)<br>(Figures 2 and 5)<br>Maximum Propagation Delay, Clock to Q<br>(Figures 2 and 5)<br>Maximum Propagation Delay, Output Enable to Q<br>(Figures 3 and 6)<br>Maximum Propagation Delay, Output Enable to Q<br>(Figures 3 and 6)<br>Maximum Output Transition Time, any Output<br>(Figures 2 and 5)<br>Maximum Input Capacitance<br>Maximum Three–State Output Capacitance, Output in High- | Maximum Clock Frequency (50% Duty Cycle)<br>(Figures 2 and 5)2.0<br>3.0<br>4.5<br>6.0Maximum Propagation Delay, Clock to Q<br>(Figures 2 and 5)2.0<br>3.0<br>4.5<br>6.0Maximum Propagation Delay, Output Enable to Q<br>(Figures 3 and 6)2.0<br>3.0<br>4.5<br>6.0Maximum Propagation Delay, Output Enable to Q<br>(Figures 3 and 6)2.0<br>3.0<br>4.5<br>6.0Maximum Propagation Delay, Output Enable to Q<br>(Figures 3 and 6)2.0<br>3.0<br>4.5<br>6.0Maximum Propagation Delay, Output Enable to Q<br>(Figures 3 and 6)2.0<br>3.0<br>4.5<br>6.0Maximum Output Transition Time, any Output<br>(Figures 2 and 5)2.0<br>3.0<br>4.5<br>6.0Maximum Input Capacitance3.0<br>4.5<br>6.0Maximum Three–State Output Capacitance, Output in High–Impedance | Parameter         V         -55 to 25°C           Maximum Clock Frequency (50% Duty Cycle)<br>(Figures 2 and 5)         2.0         6.0           Maximum Propagation Delay, Clock to Q<br>(Figures 2 and 5)         2.0         160           Maximum Propagation Delay, Clock to Q<br>(Figures 2 and 5)         2.0         160           Maximum Propagation Delay, Output Enable to Q<br>(Figures 3 and 6)         2.0         150           Maximum Propagation Delay, Output Enable to Q<br>(Figures 3 and 6)         2.0         150           Maximum Propagation Delay, Output Enable to Q<br>(Figures 3 and 6)         2.0         140           Maximum Propagation Delay, Output Enable to Q<br>(Figures 3 and 6)         2.0         140           Maximum Propagation Delay, Output Enable to Q<br>(Figures 2 and 5)         2.0         140           Maximum Output Transition Time, any Output<br>(Figures 2 and 5)         2.0         6.0         24           Maximum Input Capacitance         3.0         2.7         4.5         12           Maximum Input Capacitance         10         10         10         10 | ParameterV $-55 \text{ to } 25^{\circ}\text{C}$ $\leq 85^{\circ}\text{C}$ Maximum Clock Frequency (50% Duty Cycle)<br>(Figures 2 and 5)2.06.04.83.015104.530246.03528Maximum Propagation Delay, Clock to Q<br>(Figures 2 and 5)2.01602003.01051454.532406.02.734Maximum Propagation Delay, Output Enable to Q<br>(Figures 3 and 6)2.0150190(Figures 3 and 6)3.0100125Maximum Propagation Delay, Output Enable to Q<br>(Figures 3 and 6)2.0140175Maximum Propagation Delay, Output Enable to Q<br>(Figures 3 and 6)2.0140175Maximum Propagation Delay, Output Enable to Q<br>(Figures 2 and 5)2.01401753.02.014017530386.02.014017515(Figures 2 and 5)3.02.73232Maximum Output Transition Time, any Output<br>(Figures 2 and 5)2.06.0753.0Maximum Input Capacitance10131313Maximum Input Capacitance10101010Maximum Three-State Output Capacitance, Output in High-Impedance151515 | ParameterV-55 to $25^{\circ}$ C $\leq 85^{\circ}$ C $\leq 125^{\circ}$ CMaximum Clock Frequency (50% Duty Cycle)<br>(Figures 2 and 5)2.0<br>3.0<br>4.5<br>6.06.0<br>3.0<br>4.5<br>30<br>6.06.0<br>3.54.8<br>24<br>20<br>240Maximum Propagation Delay, Clock to Q<br>(Figures 2 and 5)2.0<br>4.5<br>3.0<br>4.5160<br>3.0<br>4.5<br>3.2240<br>240<br>48<br>441Maximum Propagation Delay, Clock to Q<br>(Figures 2 and 5)2.0<br>4.5<br>3.0<br>4.5160<br>3.0<br>4.5<br>3.2200<br>240<br>48<br>41Maximum Propagation Delay, Output Enable to Q<br>(Figures 3 and 6)2.0<br>3.0<br>4.5<br>3.0<br>4.5150<br>3.0<br>3.0<br>4.5<br>3.0<br>4.5190<br>3.0<br>3.0<br>4.5<br>3.0<br>4.5225<br>3.0<br>3.0<br>3.0<br>100<br>125<br>150<br>126150<br>140<br>125<br>150<br>140<br>125<br>150Maximum Propagation Delay, Output Enable to Q<br>(Figures 3 and 6)2.0<br>3.0<br>4.5<br>6.0140<br>26<br>3.3<br>38<br>38<br>45<br>30<br>36Maximum Propagation Delay, Output Enable to Q<br>(Figures 3 and 6)2.0<br>4.5<br>28<br>35<br>42<br>42140<br>45<br>30<br>30<br>36Maximum Output Transition Time, any Output<br>(Figures 2 and 5)2.0<br>3.0<br>4.5<br>12<br>15140<br>13<br>15Maximum Input Capacitance101010Maximum Input Capacitance101010Maximum Three-State Output Capacitance, Output in High-Impedance151515 |

### **AC ELECTRICAL CHARACTERISTICS** ( $C_L = 50 \text{ pF}$ ; Input $t_r = t_f = 6.0 \text{ ns}$ )

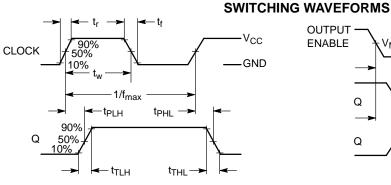
|                 |   | Typical @ 25°C, $V_{CC}$ = 5.0 V |    |
|-----------------|---|----------------------------------|----|
| C <sub>PD</sub> | Power Dissipation Capacitance (Per Enabled Output)* | 24                               | pF |

\*Used to determine the no–load dynamic power consumption:  $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$ .

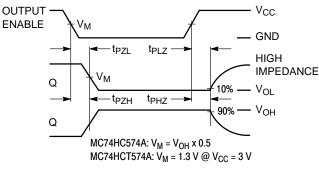
## **TIMING REQUIREMENTS** ( $C_L = 50 \text{ pF}$ ; Input $t_r = t_f = 6.0 \text{ ns}$ )

|                                 |                                   |        |                          |                          | C                         | Guarante                 | ed Limi                   | t                        |                           |      |
|---------------------------------|-----------------------------------|--------|--------------------------|--------------------------|---------------------------|--------------------------|---------------------------|--------------------------|---------------------------|------|
|                                 |                                   |        | V <sub>CC</sub>          | –55 to                   | o 25°C                    | ≤ <b>8</b>               | 5°C                       | ≤ <b>12</b>              | 5°C                       |      |
| Symbol                          | Parameter                         | Figure | Volts                    | Min                      | Max                       | Min                      | Max                       | Min                      | Max                       | Unit |
| t <sub>su</sub>                 | Minimum Setup Time, Data to Clock | 4      | 2.0<br>3.0<br>4.6<br>6.0 | 50<br>40<br>10<br>9.0    |                           | 65<br>50<br>13<br>11     |                           | 75<br>60<br>15<br>13     |                           | ns   |
| t <sub>h</sub>                  | Minimum Hold Time, Clock to Data  | 4      | 2.0<br>3.0<br>4.5<br>6.0 | 5.0<br>5.0<br>5.0<br>5.0 |                           | 5.0<br>5.0<br>5.0<br>5.0 |                           | 5.0<br>5.0<br>5.0<br>5.0 |                           | ns   |
| t <sub>w</sub>                  | Minimum Pulse Width, Clock        | 2      | 2.0<br>3.0<br>4.5<br>6.0 | 75<br>60<br>15<br>13     |                           | 95<br>80<br>19<br>16     |                           | 110<br>90<br>22<br>19    |                           | ns   |
| t <sub>r</sub> , t <sub>f</sub> | Maximum Input Rise and Fall Times | 2      | 2.0<br>3.0<br>4.5<br>6.0 |                          | 1000<br>800<br>500<br>400 |                          | 1000<br>800<br>500<br>400 |                          | 1000<br>800<br>500<br>400 | ns   |

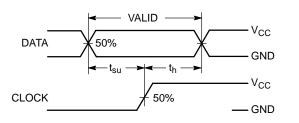
## **MC74HC574A**



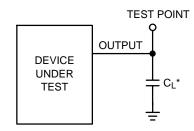






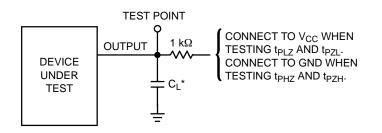






\*Includes all probe and jig capacitance.

Figure 5.



\*Includes all probe and jig capacitance.

Figure 6. Test Circuit

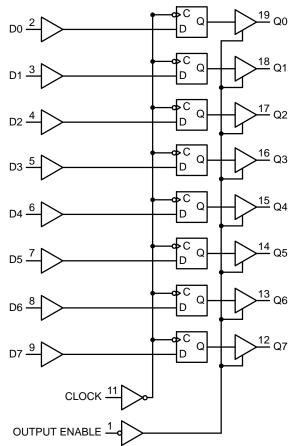


Figure 7. Expanded Logic Diagram

### **ORDERING INFORMATION**

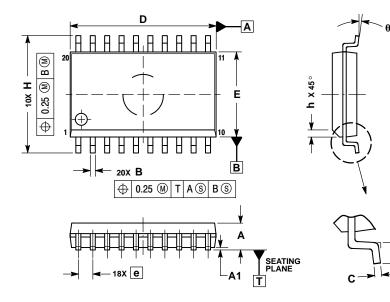
| Device            | Package                   | Shipping <sup>†</sup> |
|-------------------|---------------------------|-----------------------|
| MC74HC574ADWG     | SOIC-20 WIDE<br>(Pb-Free) | 38 Units / Rail       |
| MC74HC574ADWR2G   | SOIC-20 WIDE<br>(Pb-Free) | 1000 Tape & Reel      |
| MC74HC574ADTR2G   | TSSOP-20<br>(Pb-Free)     | 2500 Tape & Reel      |
| NLV74HC574ADTR2G* | TSSOP-20<br>(Pb-Free)     | 2500 Tape & Reel      |
| MC74HC574AFELG    | SOEIAJ-20<br>(Pb-Free)    | 2000 Tape & Reel      |

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.
 \*NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q100 Qualified and PPAP

Capable.

### PACKAGE DIMENSIONS

SOIC-20 **DW SUFFIX** CASE 751D-05 ISSUE G

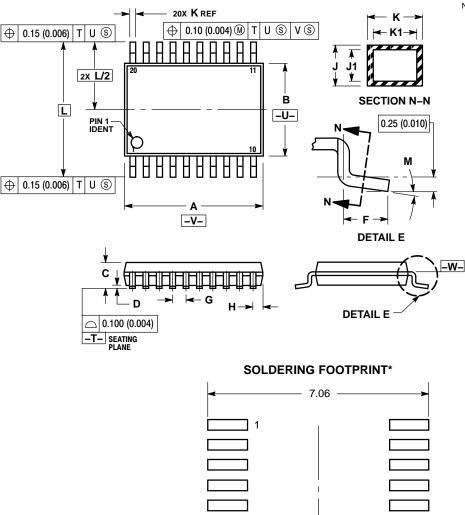


- NOTES:
  1. DIMENSIONS ARE IN MILLIMETERS.
  2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.
  3. DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSION.
  4. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
  5. DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF B DIMENSION AT MAXIMUM MATERIAL CONDITION.

|     | MILLIMETERS |       |  |  |
|-----|-------------|-------|--|--|
| DIM | MIN         | MAX   |  |  |
| Α   | 2.35        | 2.65  |  |  |
| A1  | 0.10        | 0.25  |  |  |
| В   | 0.35        | 0.49  |  |  |
| C   | 0.23        | 0.32  |  |  |
| D   | 12.65       | 12.95 |  |  |
| Е   | 7.40        | 7.60  |  |  |
| е   | 1.27        | BSC   |  |  |
| н   | 10.05       | 10.55 |  |  |
| h   | 0.25        | 0.75  |  |  |
| L   | 0.50        | 0.90  |  |  |
| θ   | 0 °         | 7 °   |  |  |

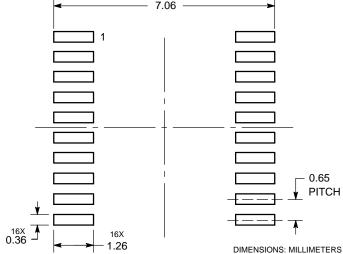
### PACKAGE DIMENSIONS

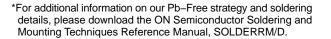
TSSOP-20 DT SUFFIX CASE 948E-02 **ISSUE C** 



- NOTES:
   DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
   CONTROLLING DIMENSION: MILLIMETER.
   DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
   DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEPED 0.25 (0.010) PER SIDE
- SHALL NOT EXCEED 0.25 (0.010) PER SIDE. 5. DIMENSION K DOES NOT INCLUDE
- DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL
- CONDITION. 6. TERMINAL NUMBERS ARE SHOWN FOR
- REFERENCE ONLY.
   DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE –W–.

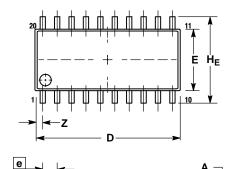
|     | MILLIMETERS |      | INCHES    |       |
|-----|-------------|------|-----------|-------|
| DIM | MIN         | MAX  | MIN       | MAX   |
| Α   | 6.40        | 6.60 | 0.252     | 0.260 |
| В   | 4.30        | 4.50 | 0.169     | 0.177 |
| C   |             | 1.20 |           | 0.047 |
| D   | 0.05        | 0.15 | 0.002     | 0.006 |
| F   | 0.50        | 0.75 | 0.020     | 0.030 |
| G   | 0.65 BSC    |      | 0.026 BSC |       |
| н   | 0.27        | 0.37 | 0.011     | 0.015 |
| J   | 0.09        | 0.20 | 0.004     | 0.008 |
| J1  | 0.09        | 0.16 | 0.004     | 0.006 |
| K   | 0.19        | 0.30 | 0.007     | 0.012 |
| K1  | 0.19        | 0.25 | 0.007     | 0.010 |
| L   | 6.40 BSC    |      | 0.252 BSC |       |
| Μ   | 0°          | 8°   | 0°        | 8°    |





#### PACKAGE DIMENSIONS

SOEIAJ-20 **F SUFFIX CASE 967 ISSUE A** 

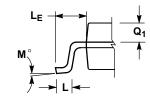


0.10 (0.004)

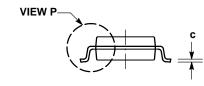
 $\frown$ 

h 0.13 (0.005) M

 $\oplus$ 



DETAIL P



NOTES

- DIMENSIONING AND TOLERANCING PER ANSI 1. Y14.5M. 1982.
- CONTROLLING DIMENSION: MILLIMETER DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS AND ARE MEASURED 3. AT THE PARTING LINE. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.15 (0.006) PER SIDE
- TERMINAL NUMBERS ARE SHOWN FOR 4
- REFERENCE ONLY. THE LEAD WIDTH DIMENSION (b) DOES NOT 5 INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE LEAD WIDTH DIMENSION AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT. MINIMUM SPACE BETWEEN PROTRUSIONS AND ADJACENT LEAD TO BE 0.46 (0.018).

|                | MILLIN   | IETERS | INCHES    |       |
|----------------|----------|--------|-----------|-------|
| DIM            | MIN      | MAX    | MIN       | MAX   |
| Α              |          | 2.05   |           | 0.081 |
| A <sub>1</sub> | 0.05     | 0.20   | 0.002     | 0.008 |
| b              | 0.35     | 0.50   | 0.014     | 0.020 |
| C              | 0.15     | 0.25   | 0.006     | 0.010 |
| D              | 12.35    | 12.80  | 0.486     | 0.504 |
| E              | 5.10     | 5.45   | 0.201     | 0.215 |
| е              | 1.27 BSC |        | 0.050 BSC |       |
| HE             | 7.40     | 8.20   | 0.291     | 0.323 |
| L              | 0.50     | 0.85   | 0.020     | 0.033 |
| LE             | 1.10     | 1.50   | 0.043     | 0.059 |
| Μ              | 0 °      | 10 °   | 0 °       | 10 °  |
| Q <sub>1</sub> | 0.70     | 0.90   | 0.028     | 0.035 |
| Z              |          | 0.81   |           | 0.032 |

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